Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length: 4.25 millimeters
Terminal Length:
25.4 millimeters
Overall Diameter:
1.85 millimeters
Function For Which Designed:
General purpose
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-35
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
17.1 regulator voltage
Voltage Tolerance In Percent:
-5.0/+5.0
Current Rating Per Characteristic:
5.00 milliamperes source cutoff current horsepower metric
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0